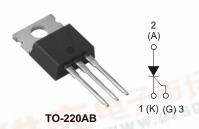


Vishay High Power Products

Phase Control SCR, 10 A



PRODUCT SUMMARY				
V _T at 10 A < 1.4 V				
I _{TSM}	200 A			
V _{RRM}	800/1200 V			

DESCRIPTION/FEATURES



The 16TTS..PbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology

used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	13.5	17	А	

PARAMETER	TEST CONDITIONS	VALUES	UNITS
I _{T(AV)}	Sinusoidal waveform	10	А
I _{RMS}	- 57	16	A
V _{DRM} /V _{RRM}	Range (1)	800/1200	V
I _{TSM}	ES TICC.COM	200	A
V _T	10 A, T _J = 25 °C	1.4	V
dV/dt		500	V/µs
dl/dt		150	A/μs
TJ	Range	- 40 to 125	°C

VOLTAGE RATINGS					
PART NUMBER VRRM, MAXIMUM PEAK REVERSE VOLTAGE V V MAXIMUM PEAK DIRECT VOLTAGE AT 12: V MAXIMUM PEAK AT 12: V					
16TTS08PbF	800	10			
16TTS12PbF	1200	1200	10		

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES		UNITS
PARAMETER	STINIBUL		TEST CONDITIONS	TYP.	MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	$I_{T(AV)}$ $T_C = 98 ^{\circ}\text{C}$, 180° conduction, half sine wave 10		0		
Maximum RMS on-state current	I _{RMS}			1	6	A
Maximum peak, one-cycle,	1	10 ms sine p	ulse, rated V _{RRM} applied	170		_ ^
non-repetitive surge current	I _{TSM}	10 ms sine p	ulse, no voltage reapplied	20	00	1
Maximum 12t for fusing	l ² t	10 ms sine p	ulse, rated V _{RRM} applied	14	44	A ² s
Maximum I ² t for fusing	I-t	10 ms sine p	ulse, no voltage reapplied	20	00	A-S
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		20	00	A²√s
Maximum on-state voltage drop	V_{TM}	10 A, T _J = 25 °C		1	.4	V
On-state slope resistance	r _t	T _J = 125 °C		24	1.0	mΩ
Threshold voltage	V _{T(TO)}			1	.1	V
Maximum rayaya and direct lackage aurent	1 /1	T _J = 25 °C	V Dated V A	0	.5	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	$V_R = Rated V_{RRM}/V_{DRM}$		1	0	
Holding current	l _Η		$v = 6 \text{ V}$, resistive load, initial $I_T = 1 \text{ A}$ 7, 16TTS12PbF	-	100	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		20	00	
Maximum rate of rise of off-state voltage	dV/dt			50	00	V/µs
Maximum rate of rise of turned-on current	dl/dt			1:	50	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	W
Maximum average gate power	P _{G(AV)}		2.0	VV
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	90	mA
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	60	
		Anode supply = 6 V, resistive load, T _J = 125 °C	35	
		Anode supply = 6 V, resistive load, T _J = - 65 °C	3.0	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	.,
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value 0.2 2.0		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs
Typical turn-off time	t _q	1 1 = 125 0	110	

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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.3	
Maximum thermal resistance, junction to ambient		R_{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5	
Annravimata waight				2	g
Approximate weight				0.07	OZ.
Mounting torque ————	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220AB	16T	TS08
				16T	16TTS12

Vishay High Power Products Phase Control SCR, 10 A



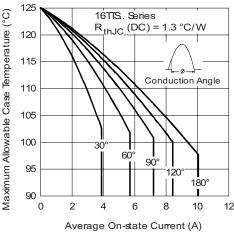


Fig. 1 - Current Rating Characteristics

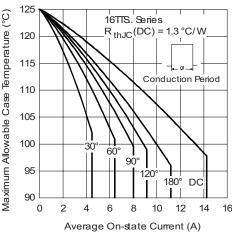
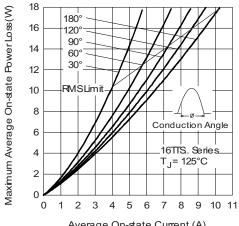


Fig. 2 - Current Rating Characteristics



Average On-state Current (A) Fig. 3 - On-State Power Loss Characteristics

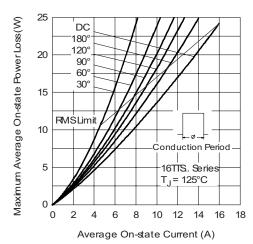
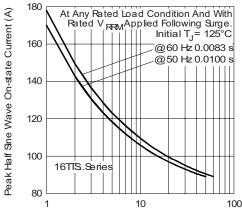


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

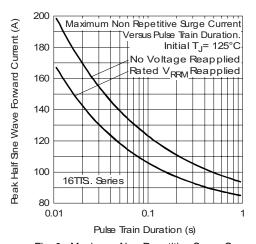


Fig. 6 - Maximum Non-Repetitive Surge Current

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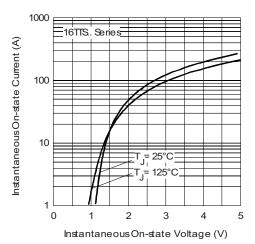


Fig. 7 - On-State Voltage Drop Characteristics

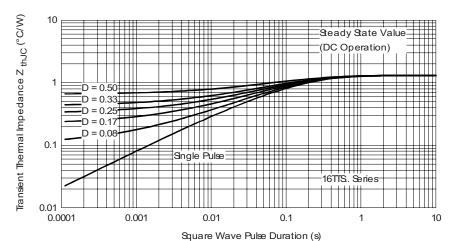


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

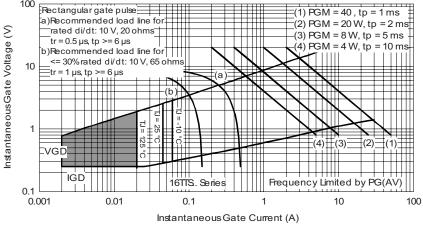


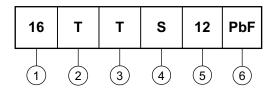
Fig. 9 - Gate Characteristics

Vishay High Power Products Phase Control SCR, 10 A



ORDERING INFORMATION TABLE

Device code



1 - Current rating

2 - Circuit configuration:

T = Single thyristor

- Package:

T = TO-220AB

4 - Type of silicon:

S = Converter grade

5 - Voltage code x 100 = V_{RRM} -

08 = 800 V 12 = 1200 V

6 - • None = Standard production

• PbF = Lead (Pb)-free

Note: For higher voltage up to 1600 V contact factory

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95222				
Part marking information	http://www.vishay.com/doc?95225			

www.vishay.com For technical questions, contact: diodes-tech@vishay.com

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